

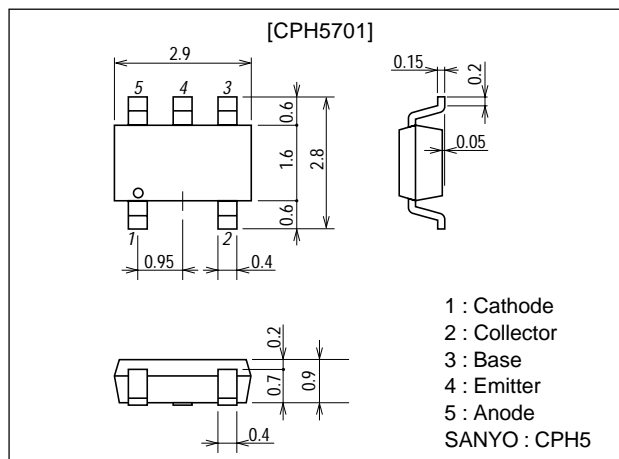
**CPH5701****DC/DC Converter Applications****Features**

- Composite type with a PNP transistor and a Schottky barrier diode contained in one package facilitating high-density mounting.
- Each device incorporated in the CPH5701 is equivalent to the CPH3106 and to the SBS004, respectively.
- Ultrasmall package facilitates miniaturization in end products.

Package Dimensions

unit:mm

2156

**Specifications****Absolute Maximum Ratings** at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
[TR]				
Collector-to-Base Voltage	V_{CBO}		-15	V
Collector-to-Emitter Voltage	V_{CEO}		-12	V
Emitter-to-Base Voltage	V_{EBO}		-5	V
Collector Current	I_C		-3	A
Collector Current (Pulse)	I_{CP}		-5	A
Base Current	I_B		-600	mA
Collector Dissipation	P_C	Mounted on a ceramic board (600mm ² ×0.8mm)	0.9	W
Junction Temperature	T_J		150	°C
Storage Temperature	T_{stg}		-55 to +125	°C
[SBD]				
Repetitive Peak Reverse Voltage	V_{RRM}		15	V
Non-repetitive Peak Reverse Surge Voltage	V_{RSM}		15	V
Average Output Current	I_O		1	A
Surge Current	I_{FSM}	50Hz sine wave, 1 cycle	10	A
Junction Temperature	T_J		-55 to +125	°C
Storage Temperature	T_{stg}		-55 to +125	°C

■ Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.

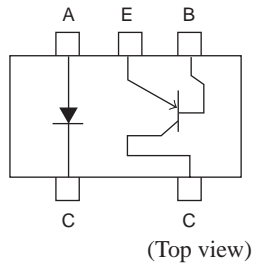
■ SANYO assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO products described or contained herein.

CPH5701

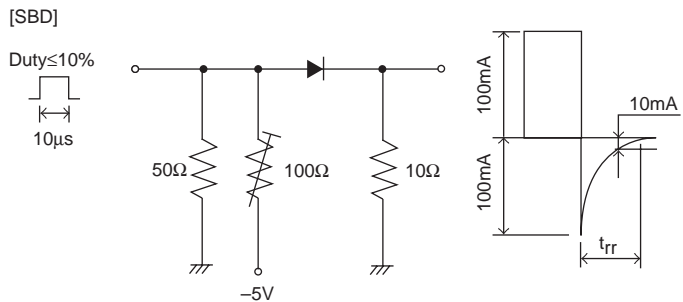
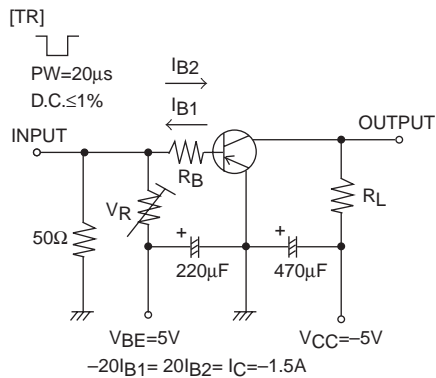
Electrical Characteristics at $T_a = 25^\circ\text{C}$

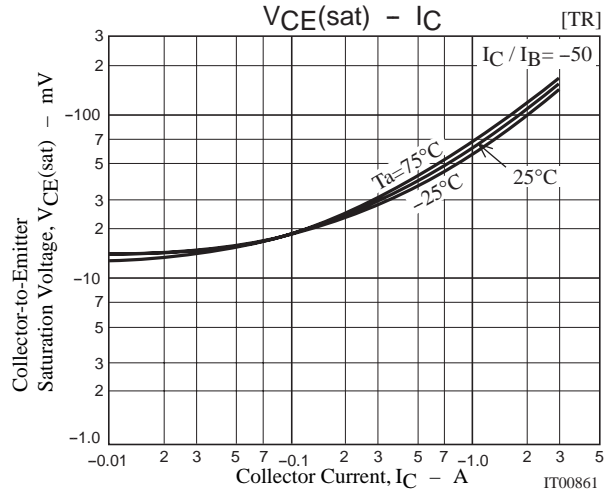
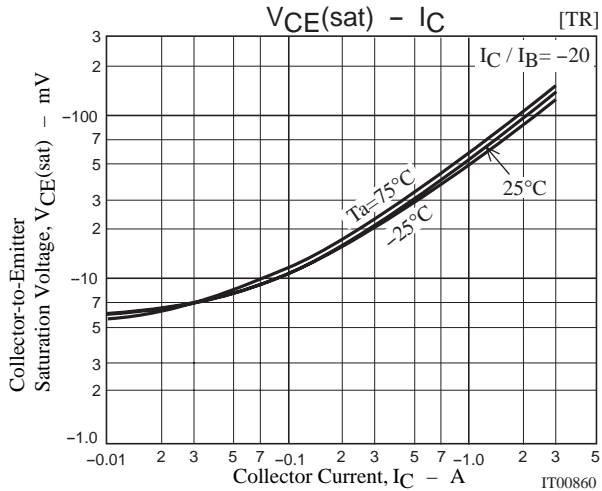
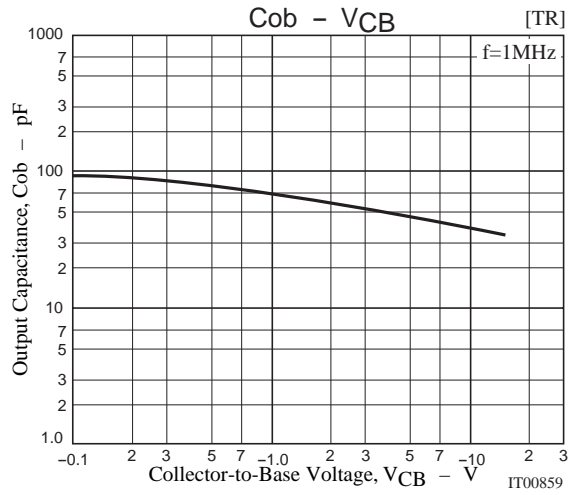
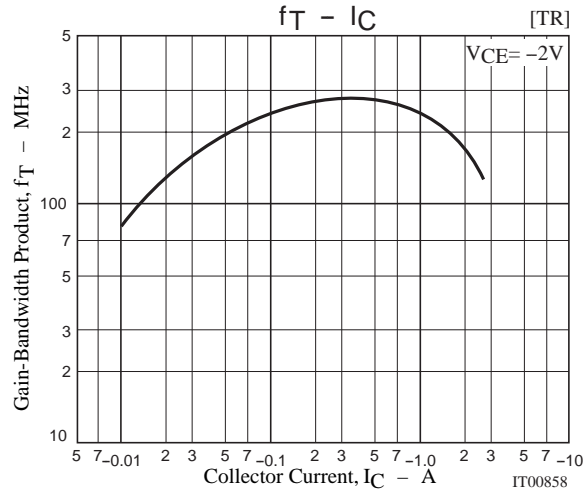
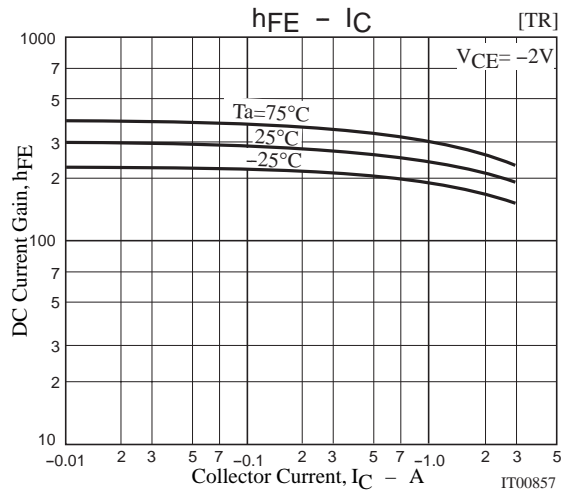
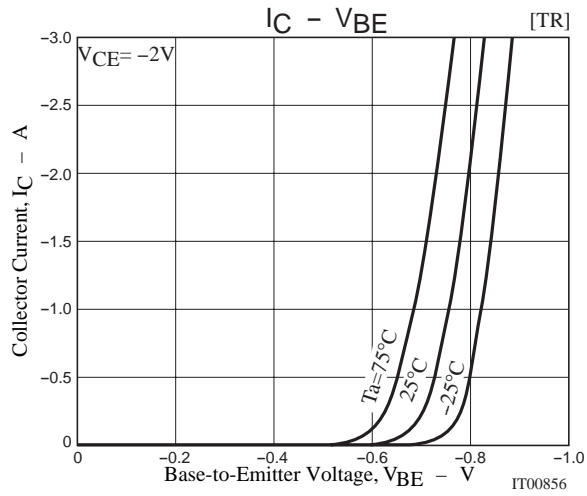
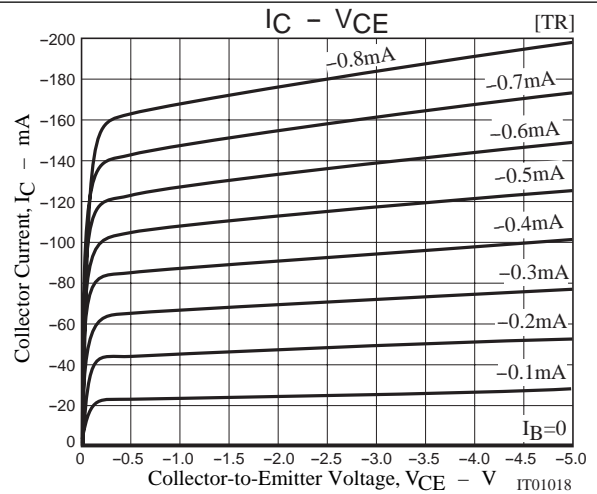
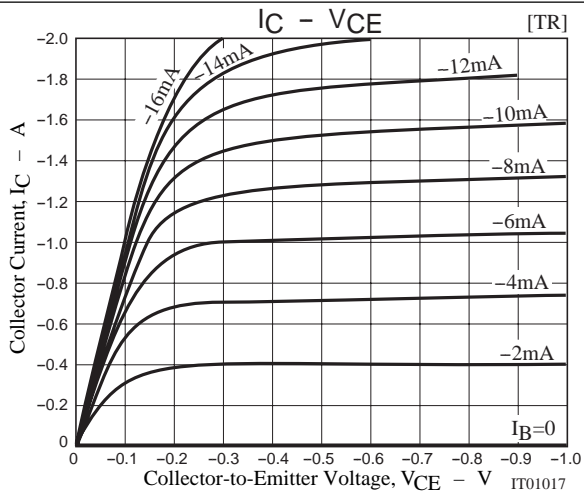
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[TR]						
Collector Cutoff Current	I_{CBO}	$V_{CB}=-12V, I_E=0$			-0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=-4V, I_C=0$			-0.1	μA
DC Current Gain	h_{FE1}	$V_{CE}=-2V, I_C=-0.5A$	200		560	
	h_{FE2}	$V_{CE}=-2V, I_C=-3A$	70			
Gain-Bandwidth Product	f_T	$V_{CE}=-2V, I_C=-0.5A$		280		MHz
Output Capacitance	C_{ob}	$V_{CB}=-10V, f=1MHz$		36		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-1.5A, I_B=-30mA$		-110	-165	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=-1.5A, I_B=-30mA$		-0.85	-1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=-10\mu A, I_E=0$	-15			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-1mA, R_{BE}=\infty$	-12			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-10\mu A, I_C=0$	-5			V
Turn-ON Time	t_{on}	See specified Test Circuit.		30		ns
Storage Time	t_{stg}	See specified Test Circuit.		90		ns
Fall Time	t_f	See specified Test Circuit.		10		ns
[SBD]						
Reverse Voltage	V_R	$I_R=1mA$	15			V
Forward Voltage	V_{F1}	$I_F=0.5A$		0.30	0.35	V
	V_{F2}	$I_F=1A$		0.35	0.40	V
Reverse Current	I_R	$V_R=6V$			500	μA
Interterminal Capacitance	C	$V_R=10V, f=1MHz$		42		pF
Reverse Recovery Time	t_{rr}	$I_F=I_R=100mA$, See specified Test Circuit.			15	ns
Thermal Resistance	R_{thj-a}	Mounted on a ceramic board (600mm ² ×0.8mm)		110		$^{\circ}C/W$

Electrical Connection

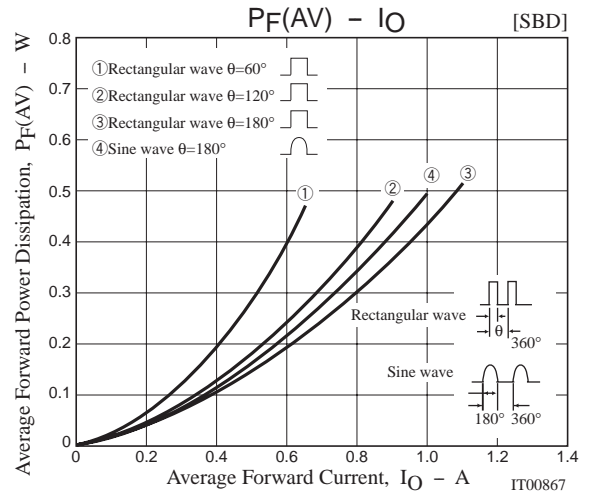
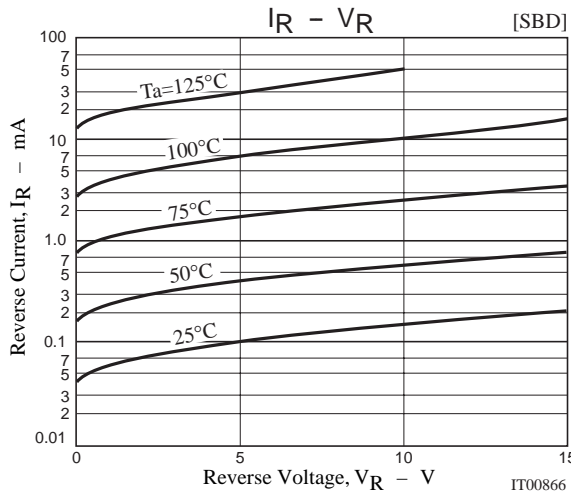
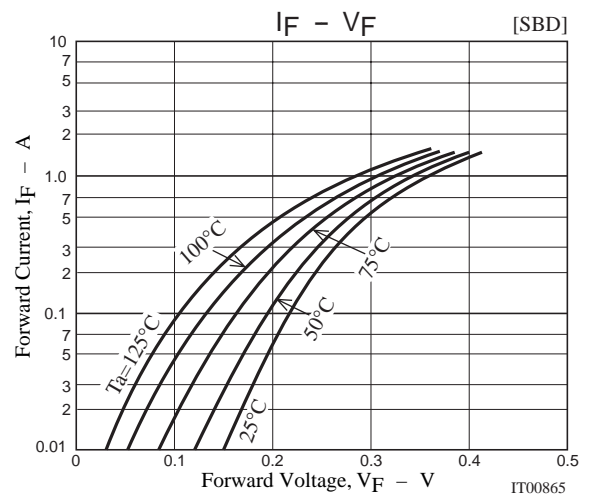
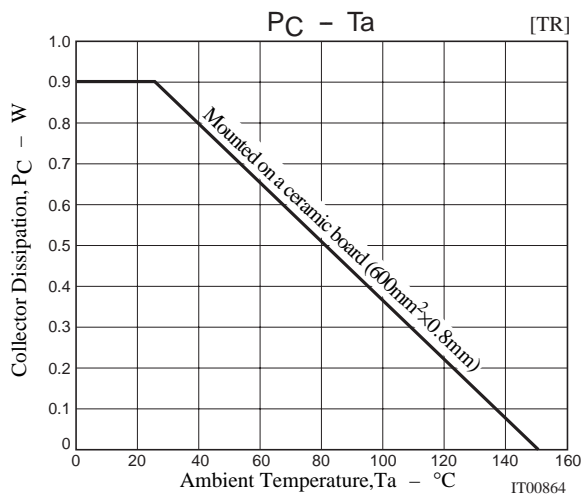
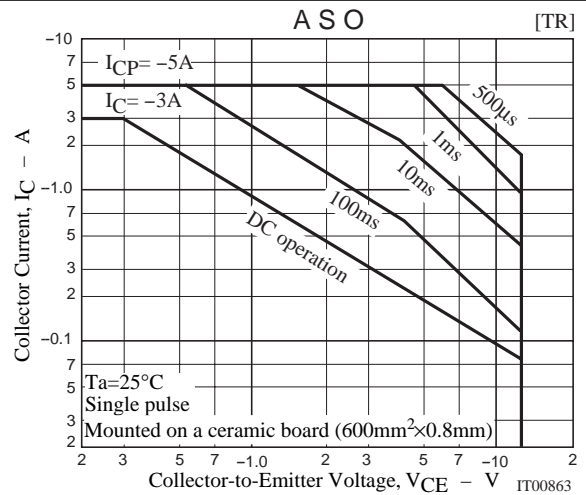
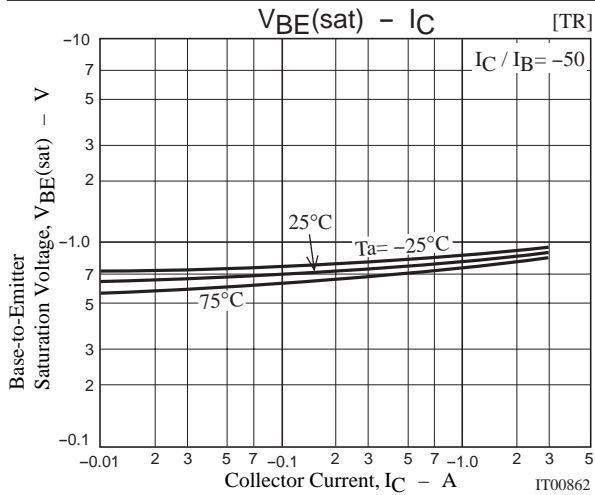


Switching Time Test Circuit





CPH5701



- Specifications of any and all SANYO products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Electric Co., Ltd. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of SANYO Electric Co., Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of July, 2000. Specifications and information herein are subject to change without notice.